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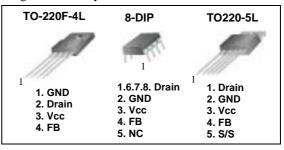
KA5x02xx-SERIES KA5H0265RC, KA5M0265R, KA5L0265R, KA5H02659RN/KA5M02659RN, KA5H0280R, KA5M0280R Fairchild Power Switch(FPS)

Features

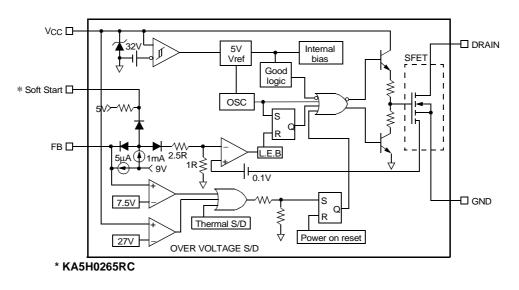
- Precision Fixed Operating Frequency (100/67/50kHz)
- Low Start-up Current (Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry-compared to discrete MOSFET and controller or R_{CC} switching converter solution. The Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for cost-effective design in either a flyback converter or a forward converter.



Internal Block Diagram



Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit	
KA5x0265xRx				
Drain-Gate Voltage (R _{GS} =1MΩ)	Vdgr	650	V	
Gate-Source (GND) Voltage	VGS	±30	V	
Drain Current Pulsed ⁽¹⁾	IDM	8.0	ADC	
Continuous Drain Current (T _C =25°C)	۱D	2.0	ADC	
Continuous Drain Current (Tc=100°C)	ID	1.3	ADC	
Single Pulsed Avalanche Energy ⁽²⁾	EAS	68	mJ	
Maximum Supply Voltage	VCC,MAX	30	V	
Analog Input Voltage Range	VFB	-0.3 to VSD	V	
Total Power Dissipation	PD	42	W	
	Darting	0.33	W/°C	
Operating Junction Temperature.	TJ	+160	°C	
Operating Ambient Temperature.	TA -25 to +85		°C	
Storage Temperature Range.	TSTG -55 to +150		°C	
KA5x0280R		<u> </u>		
Drain-Gate Voltage (R _{GS} =1MΩ)	VDGR 800		V	
Gate-Source (GND) Voltage	VGS ±30		V	
Drain Current Pulsed (1)	IDM	8.0	ADC	
Continuous Drain Current (T _C =25°C)	ID	2.0	ADC	
Continuous Drain Current (T _C =100°C)	ID	1.3	ADC	
Single Pulsed Avalanche Energy (2)	EAS	90	mJ	
Maximum Supply Voltage	VCC,MAX	30	V	
Analog Input Voltage Range	VFB	-0.3 to V _{SD}	V	
Total Power Discipation	PD	35	W	
Total Power Dissipation	Darting	0.28	W/°C	
Operating Junction Temperature.	TJ	+160	°C	
Operating Ambient Temperature.	TA	-25 to +85	°C	
Storage Temperature Range.	TSTG	-55 to +150	۵°	

Note:

1. Repetitive rating: Pulse width limited by maximum junction temperature

2. L = 51mH, starting Tj = $25^{\circ}C$

Electrical Characteristics (SFET Part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
KA5x0265xRx						
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50μA	650	-	-	V
	IDSS	VDS=Max. Rating, VGS=0V	-	-	50	μA
Zero Gate Voltage Drain Current		V _{DS} =0.8Max. Rating, V _{GS} =0V, T _C =125°C	-	-	200	μA
Static Drain-Source on Resistance (Note)	RDS(ON)	VGS=10V, ID=0.5A	-	5.0	6.0	Ω
Forward Transconductance (Note)	gfs	V _{DS} =50V, I _D =0.5A	1.5	2.5	-	S
Input Capacitance	Ciss		-	550	-	pF
Output Capacitance	Coss	VGS=0V, VDS=25V, f=1MHz	-	38	-	
Reverse Transfer Capacitance	Crss		-	17	-	
Turn on Delay Time	td(on)	VDD=0.5B VDSS, ID=1.0A	-	20	-	nS
Rise Time	tr	(MOSFET switching time is	-	15	-	
Turn Off Delay Time	td(off)	essentially independent of	-	55	-	
Fall Time	tf	operating temperature)	-	25	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	V _{GS} =10V, I _D =1.0A, V _{DS} =0.5B V _{DSS} (MOSFET	-	-	35	nC
Gate-Source Charge	Qgs	switching time is essentially		3	_	
Gate-Drain (Miller) Charge	Qgd	independent of operating temperature)	_	12	_	
KA5x0280R	9-	temperature)				
			800	-		V
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50µA			-	
Zero Gate Voltage Drain Current	IDSS	VDS=Max. Rating, VGS=0V VDS=0.8Max. Rating, VGS=0V, TC=125°C	-	-	50 200	μA μA
Static Drain-Source on Resistance (Note)	RDS(ON)	VGS=10V, ID=0.5A	-	5.6	7.0	Ω
Forward Transconductance (Note)	gfs	VDS=50V, ID=0.5A	1.5	2.5	-	S
Input Capacitance	Ciss		-	250	-	pF
Output Capacitance	Coss	VGS=0V, VDS=25V, f=1MHz	-	52	-	
Reverse Transfer Capacitance	Crss		-	25	-	
Turn on Delay Time	td(on)		-	21	-	
Rise Time	tr	VDD=0.5B VDSS, ID=1.0A (MOSFET switching time is	-	28	-	- nS
Turn Off Delay Time	td(off)	essentially independent of	-	77	-	
Fall Time	tf	operating temperature)	-	24	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	V _{GS} =10V, I _D =1.0A, V _{DS} =0.5B V _{DSS} (MOSFET	-	-	60	
Gate-Source Charge	Qgs	switching time is essentially	-	15	-	nC
Gate-Drain (Miller) Charge	Qgd	independent of operating temperature)	-	20	-	

Note:

1. Pulse test: Pulse width $\leq 300 \mu S,$ duty cycle $\leq 2\%$

^{2.} S = $\frac{1}{R}$

Electrical Characteristics (Control Part) (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit		
UVLO SECTION								
Start Threshold Voltage	VSTART	VFB=GND	14	15	16	V		
Stop Threshold Voltage	VSTOP	V _{FB} =GND	8.2	8.8	9.4	V		
OSCILLATOR SECTION								
Initial Accuracy	Fosc	KA5H0265xRx KA5H0280R	90	100	110	kHz		
Initial Accuracy	Fosc	KA5M0265xRx KA5M0280R	61	67	73	kHz		
Initial Accuracy	Fosc	KA5L0265R	45	50	55	kHz		
Frequency Change With Temperature (2)	$\Delta F / \Delta T$	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%		
Maximum Duty Cycle	Dmax	KA5H0265xRx KA5H0280R	62	67	72	%		
Maximum Duty Cycle	Dmax	KA5M0265xRx KA5M0280R KA5L0265R	72	77	82	%		
FEEDBACK SECTION						•		
Feedback Source Current	IFB	Ta=25°C, $0V \le Vfb \le 3V$	0.7	0.9	1.1	mA		
Shutdown Feedback Voltage	VSD	$V f b \le 6.5 V$	6.9	7.5	8.1	V		
Shutdown Delay Current	Idelay	Ta=25°C, 5V \leq Vfb \leq V _{SD}	4	5	6	μΑ		
SOFT START SECTION								
Soft Start Voltage	Vss	KA5H0265RC	4.7	5.0	5.3	V		
Soft Start Current	Iss	NASH0205NO	0.8	1.0	1.2	mA		
REFERENCE SECTION								
Output Voltage ⁽¹⁾	Vref	Ta=25°C	4.80	5.00	5.20	V		
Temperature Stability ⁽¹⁾⁽²⁾	Vref/∆T	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C		
CURRENT LIMIT(SELF-PROTECTION)S	SECTION							
Peak Current Limit	IOVER	KA5x02659RN	0.79	0.9	1.01	Α		
Peak Current Limit	IOVER	KA5x0265Rx KA5x0280R	1.05	1.2	1.34	A		
PROTECTION SECTION		•			•	•		
Over Voltage Protection	Vovp	$VCC \ge 24V$	25	27	29	V		
Thermal Shutdown Temperature ⁽¹⁾	T _{SD}	-	140	160	-	°C		
TOTAL DEVICE SECTION								
Start-up Current	ISTART	V _{CC} =14V	-	100	170	μA		
Operating Supply Current (Control Part Only)	IOPR	V _{CC} ≤ 28	-	7	12	mA		

Note:

1. These parameters, although guaranteed, are not 100% tested in production

2. These parameters, although guaranteed, are tested in EDS (wafer test) process

Typical Performance Characteristics

(These characteristic graphs are normalized at Ta=25°C)

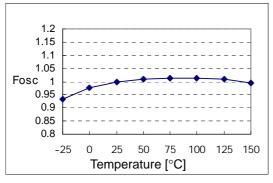


Figure 1. Operating Frequency

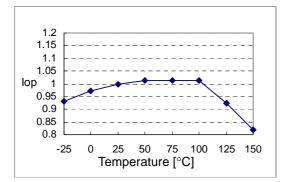


Figure 3. Operating Supply Current

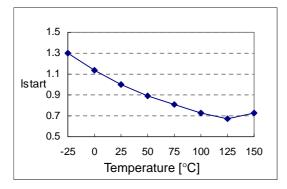


Figure 5. Start up Current

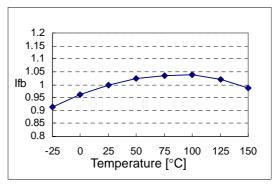


Figure 2. Feedback Source Current

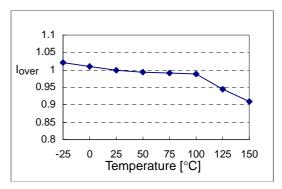


Figure 4. Peak Current Limit

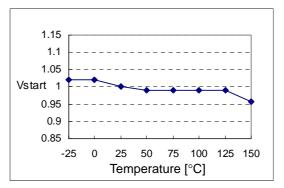


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

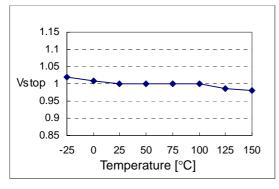


Figure 7. Stop Threshold Voltage

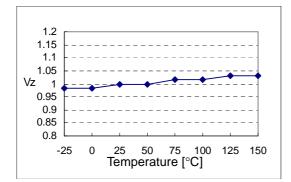


Figure 9. VCC Zener Voltage

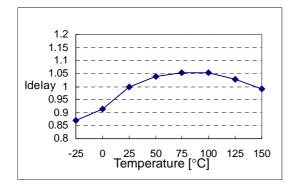


Figure 11. Shutdown Delay Current

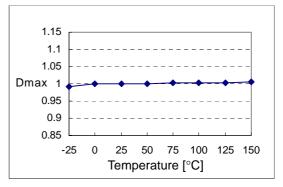


Figure 8. Maximum Duty Cycle

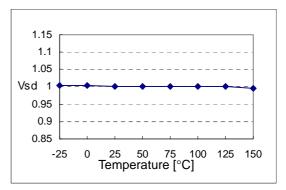


Figure 10. Shutdown Feedback Voltage

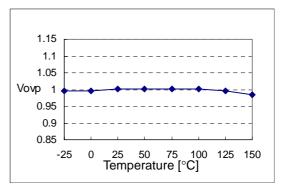


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

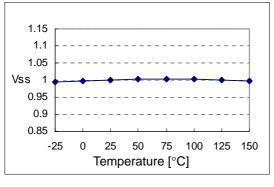


Figure13. Soft Start Voltage

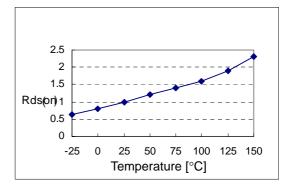
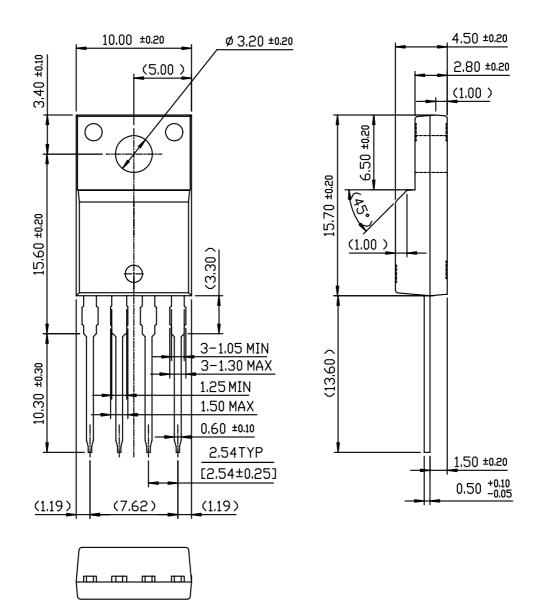


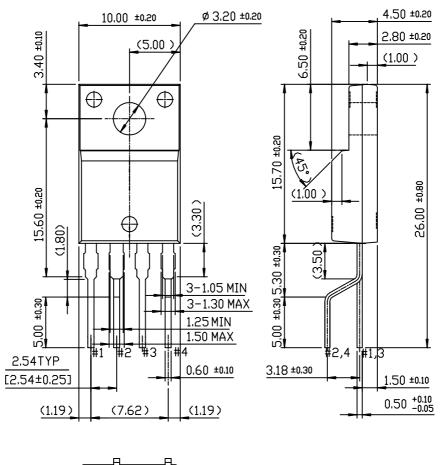
Figure 14. Static Drain-Source on Resistance

Package Dimensions



TO-220F-4L

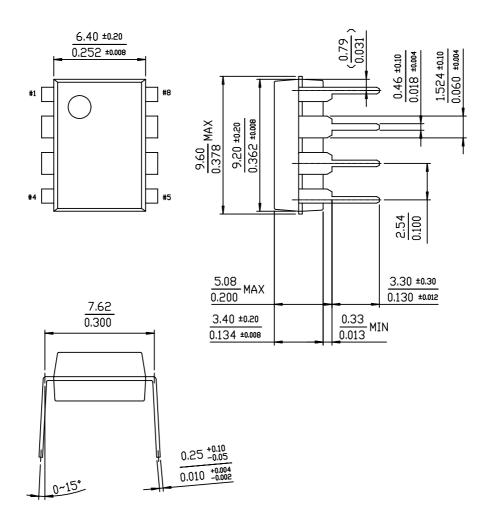
TO-220F-4L(Forming)



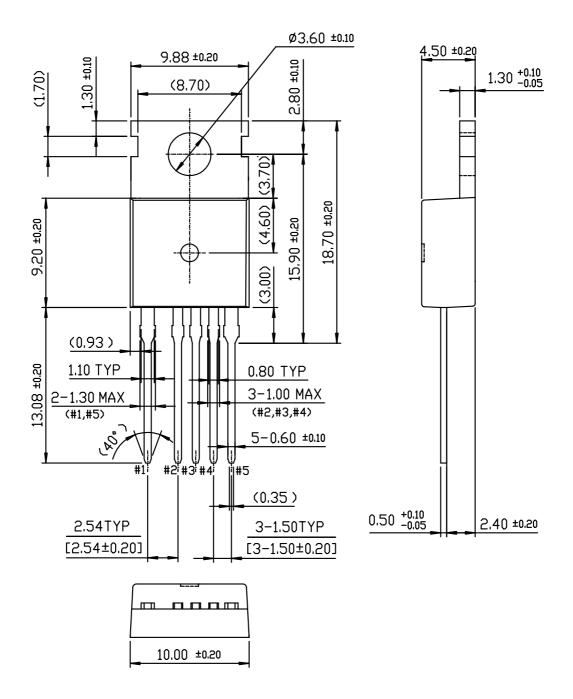
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Package Dimensions (Continued)



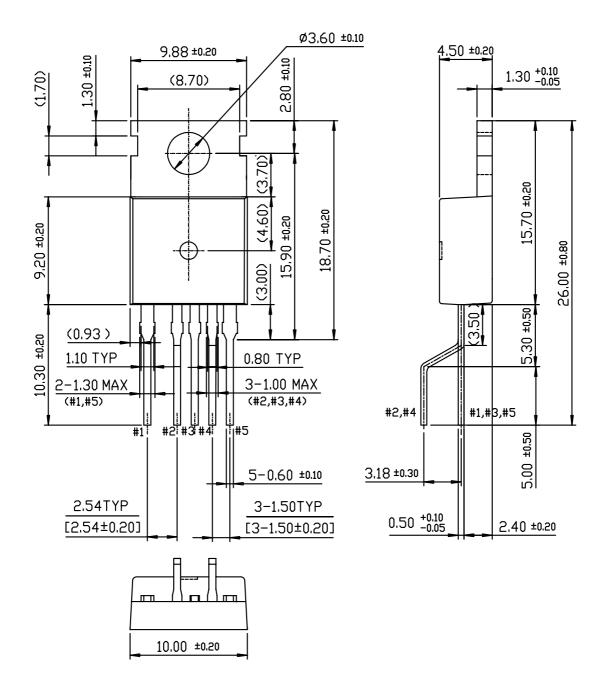






Package Dimensions (Continued)





Ordering Information

Product Number	Package	Marking Code	BVDSS	Fosc	RDS(on)	
KA5H0265RCTU	TO-220-5L	5H0265RC	65RC 650V	100kHz	5Ω	
KA5H0265RCYDTU	TO-220-5L(Forming)	5H0205KC	050 V	TUUKHZ		
KA5M0265RTU	TO-220F-4L	5M0265R	650V	67kHz	FO	
KA5M0265RYDTU	TO-220F-4L(Forming)	2110202K	0000	07KHZ	5Ω	
KA5L0265RTU	TO-220F-4L	5L0265R 650V			50	
KA5L0265RYDTU	TO-220F-4L(Forming)	5L0205R	650V	50kHz	5Ω	
Product Number	Package	Marking Code	BVDSS	Fosc	RDS(on)	
KA5H0280RTU	TO-220F-4L	5U0290D	5H0280R 800V	100kHz	5.6Ω	
KA5H0280RYDTU	TO-220F-4L(Forming)	300200K			5.012	
KA5M0280RTU	TO-220F-4L	5M0280R 800V	67kHz	E GO		
KA5M0280RYDTU	TO-220F-4L(Forming)	JIVIU20UR	8007	07 KHZ	5.6Ω	
Product Number	Package	Marking Code	BVDSS	Fosc	RDS(on)	
KA5H02659RN	8-DIP	5H02659R	650V	100kHz	5Ω	
KA5M02659RN	8-DIP	5M02659R	650V	67kHz	5Ω	

TU : Non Forming Type YDTU : Forming Type

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